



Fast Recovery Diode

 V_{RRM}

F(AV)

Replaces January 2000 version, DS4142-5.0

DS4143-6.0 June 2004

1600V

295A

3500A

25μC 1.22μs

KEY PARAMETERS

FEATURES

- Double Side Cooling
- High Surge Capability
- Low Recovery Charge

APPLICATIONS

- Induction Heating
- A.C. Motor Drives
- Inverters And Choppers
- Welding
- High Frequency Rectification
- UPS

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V _{RRM} V	Conditions
DF451 16	1600	$V_{RSM} = V_{RRM} + 100V$
DF451 14	1400	now nnw
DF451 12	1200	
DF451 10	1000	
DF451 08	800	
DF451 06	600	

Outline type code: M771. See Package Details for further information.

Fig. 1 Package outline

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table, e.g.:

DF451 12

Note: Please use the complete part number when ordering and quote this number in any future correspondance relating to your order.



CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units			
Double Sid	Double Side Cooled						
I _{F(AV)}	Mean forward current	Half wave resistive load, T _{case} = 65°C	295	Α			
I _{F(RMS)}	RMS value	T _{case} = 65°C	543	Α			
I _F	Continuous (direct) forward current	T _{case} = 65°C	391	Α			
Single Side Cooled (Anode side)							
I _{F(AV)}	Mean forward current	Half wave resistive load, T _{case} = 65°C	220	А			
I _{F(RMS)}	RMS value	T _{case} = 65°C	348	Α			
I _F	Continuous (direct) forward current	T _{case} = 65°C	285	Α			

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 0% V T = 150°C	3.5	kA
l ² t	I ² t for fusing	10ms half sine; with 0% V _{RRM,} T _j = 150°C	61.25 x 10 ³	A ² s
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine; with 50% V _{RRM.} T _i = 150°C	2.8	kA
l ² t	I ² t for fusing	Tomis man sine, with 50% \mathbf{v}_{RRM} , $\mathbf{r}_j = 150$ C	39.2 x 10 ³	A ² s

THERMAL AND MECHANICAL DATA

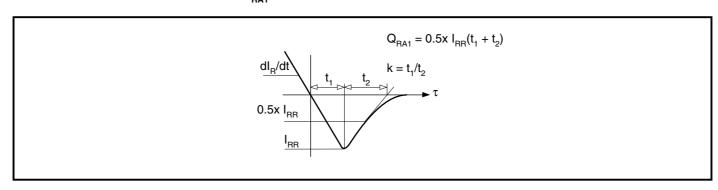
Symbol	Parameter	Conditions		-	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.07	°C/W
		Single side cooled	Anode dc	-	0.133	°C/W
			Cathode dc	-	0.147	°C/W
В	Thermal resistance - case to heatsink	Clamping force 5.0kN with mounting compound	Double side	-	0.02	°C/W
$R_{th(c-h)}$			Single side	-	0.02	°C/W
T _{vj}	Virtual junction temperature	Forward (conducting)		-	150	°C
T _{stg}	Storage temperature range			-55	150	°C
-	Clamping force			4.5	5.5	kN



CHARACTERISTICS

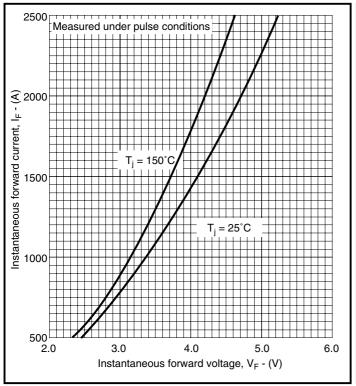
Symbol	Parameter	Conditions	Тур.	Max.	Units
V _{FM}	Forward voltage	At 600A peak, T _{case} = 25°C	-	2.65	V
I _{RRM}	Peak reverse current	At V _{RRM} , T _{case} = 125°C	-	100	mA
t _{rr}	Reverse recovery time		1.22	-	μs
Q _{RA1}	Recovered charge (50% chord)	$I_{\rm F} = 500$ A, $di_{\rm RR}/dt = -80$ A/ μ s	-	25	μC
I _{RM}	Reverse recovery current	$T_{case} = 125^{\circ}C, V_{R} = 100V$	-	40	Α
К	Soft factor		1.7	-	-
V _{TO}	Threshold voltage	At T _{vj} = 125°C	-	1.6	٧
r _T	Slope resistance	At T _{vj} = 125°C	-	1.5	mΩ
V _{FRM}	Forward recovery voltage	di/dt = 1000A/ μ s, T _j = 125°C	-	40	V

DEFINITION OF K FACTOR AND $\boldsymbol{Q}_{\text{RA1}}$





CURVES



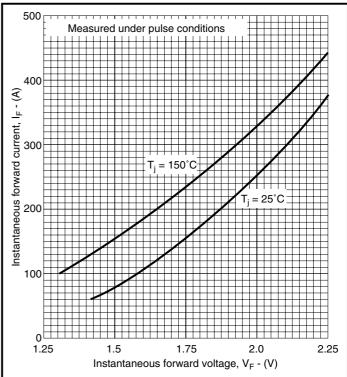
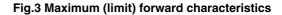
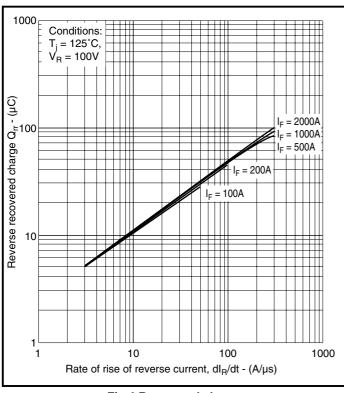


Fig.2 Maximum (limit) forward characteristics







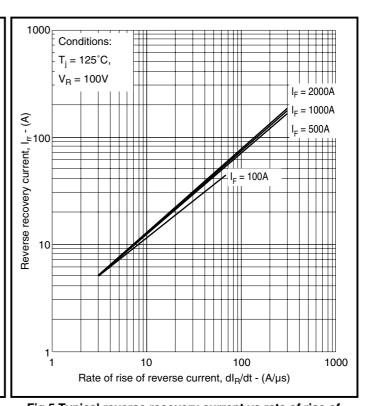


Fig.5 Typical reverse recovery current vs rate of rise of forward current



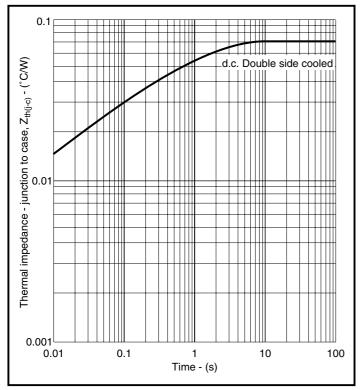
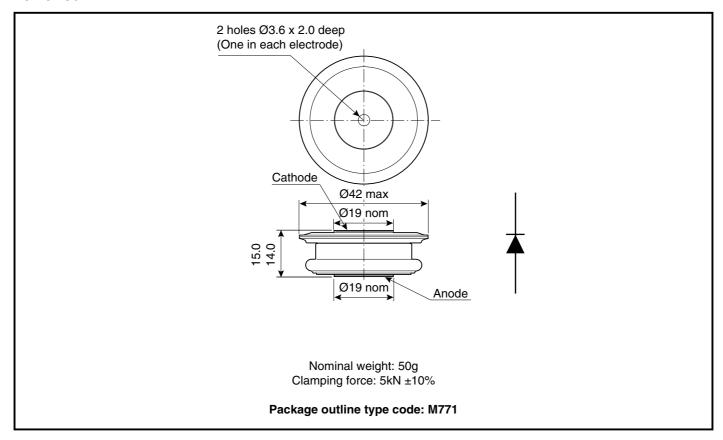


Fig.6 Maximum (limit) transient thermal impedance - junction to case - (°C/W)



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.

Stresses above those listed in this data sheet may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed.



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